

M63802P/FP/GP/KP

7-UNIT 300mA TRANSISTOR ARRAY

DESCRIPTION

M63802P, M63802FP, M63802GP and M63802KP are seven-circuit single transistor arrays. The circuits are made of NPN transistors. Both the semiconductor integrated circuits perform high-current driving with extremely low input-current supply.

FEATURES

- Four package configurations (P, FP, GP and KP)
- Medium breakdown voltage ($BV_{CEO} \geq 35V$)
- Synchronizing current ($I_{C(max)} = 300mA$)
- With zener diodes
- Low output saturation voltage
- Wide operating temperature range ($T_a = -40$ to $+85^\circ C$)

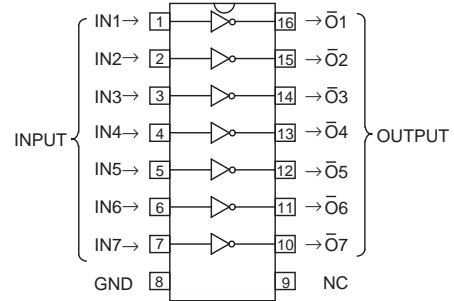
APPLICATION

Driving of digit drives of indication elements (LEDs and lamps) with small signals

FUNCTION

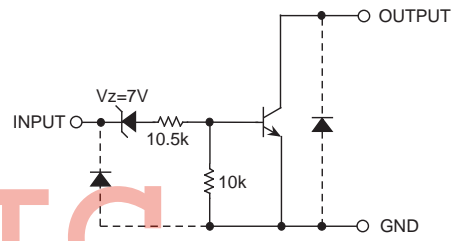
The M63802P, M63802FP, M63802GP and M63802KP each have seven circuits consisting of NPN transistor. The transistor emitters are all connected to the GND pin (pin 8). The transistors allow synchronous flow of 300mA collector current. A maximum of 35V voltage can be applied between the collector and emitter.

PIN CONFIGURATION



Package type 16P4(P)
 16P2N-A(FP)
 16P2S-A(GP)
 16P2Z-A(KP) NC : No connection

CIRCUIT DIAGRAM



The seven circuits share the GND.

The diode, indicated with the dotted line, is parasitic, and cannot be used.

Unit: Ω

ABSOLUTE MAXIMUM RATINGS (Unless otherwise noted, $T_a = -40 \sim +85^\circ C$)

| Symbol | Parameter | Conditions | Ratings | Unit | |
|-----------|---------------------------|--|------------|------------|---|
| V_{CEO} | Collector-emitter voltage | Output, H | -0.5 ~ +35 | V | |
| I_C | Collector current | Current per circuit output, L | 300 | mA | |
| V_i | Input voltage | | -0.5 ~ +35 | V | |
| P_d | Power dissipation | $T_a = 25^\circ C$, when mounted on board | M63802P | 1.47 | W |
| | | | M63802FP | 1.00 | |
| | | | M63802GP | 0.80 | |
| | | | M63802KP | 0.78 | |
| T_{opr} | Operating temperature | | -40 ~ +85 | $^\circ C$ | |
| T_{stg} | Storage temperature | | -55 ~ +125 | $^\circ C$ | |

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RECOMMENDED OPERATING CONDITIONS (Unless otherwise noted, Ta = -40 ~ +85°C)

| Symbol | Parameter | Test conditions | Limits | | | Unit | |
|-----------------|--|-----------------|------------------------------|-----|-----|------|----|
| | | | min | typ | max | | |
| V _o | Output voltage | | 0 | — | 35 | V | |
| I _c | Collector current (Current per 1 circuit when 7 circuits are coming on simulta- neously) | M63802P | Duty Cycle no more than 45% | 0 | — | 250 | mA |
| | | | Duty Cycle no more than 100% | 0 | — | 160 | |
| | | M63802FP | Duty Cycle no more than 30% | 0 | — | 250 | |
| | | | Duty Cycle no more than 100% | 0 | — | 130 | |
| | | M63802GP | Duty Cycle no more than 24% | 0 | — | 250 | |
| | | | Duty Cycle no more than 100% | 0 | — | 120 | |
| M63802KP | Duty Cycle no more than 24% | 0 | — | 250 | | | |
| | Duty Cycle no more than 100% | 0 | — | 120 | | | |
| V _{IN} | Input voltage | | 0 | — | 30 | V | |

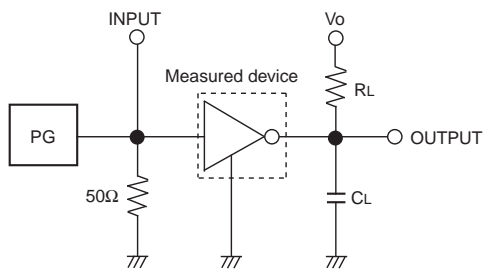
ELECTRICAL CHARACTERISTICS (Unless otherwise noted, Ta = 25°C)

| Symbol | Parameter | Test conditions | Limits | | | Unit |
|----------------------|--------------------------------------|---|--------|-----|-----|------|
| | | | min | typ | max | |
| V (BR) CEO | Collector-emitter breakdown voltage | I _{CEO} = 10μA | 35 | — | — | V |
| V _{CE(sat)} | Collector-emitter saturation voltage | I _{IN} = 1mA, I _c = 10mA | — | — | 0.2 | V |
| | | I _{IN} = 2mA, I _c = 150mA | — | — | 0.8 | |
| V _{IN(on)} | "On" input voltage | I _{IN} = 1mA, I _c = 10mA | 13 | 19 | 23 | V |
| h _{FE} | DC amplification factor | V _{CE} = 10V, I _c = 10mA | 50 | — | — | — |

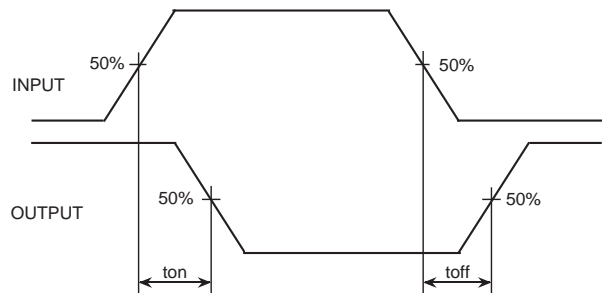
SWITCHING CHARACTERISTICS (Unless otherwise noted, Ta = 25°C)

| Symbol | Parameter | Test conditions | Limits | | | Unit |
|------------------|---------------|--------------------------------|--------|-----|-----|------|
| | | | min | typ | max | |
| t _{on} | Turn-on time | C _L = 15pF (note 1) | — | 140 | — | ns |
| t _{off} | Turn-off time | | — | 240 | — | ns |

NOTE 1 TEST CIRCUIT



TIMING DIAGRAM

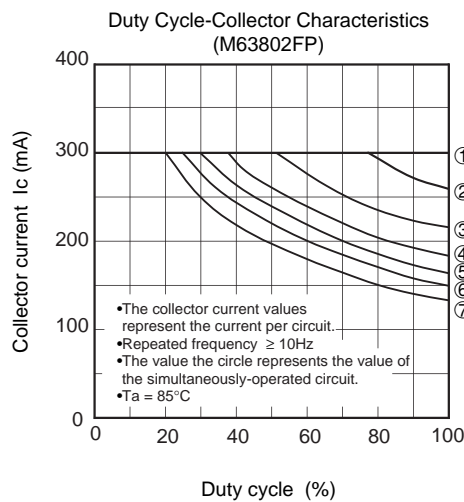
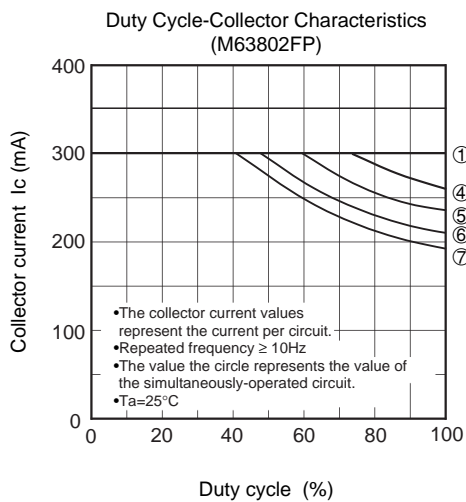
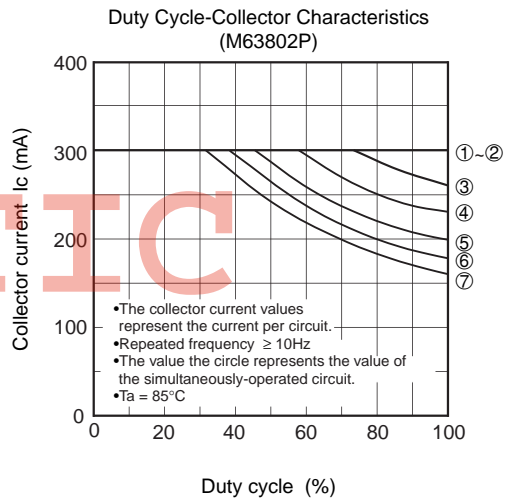
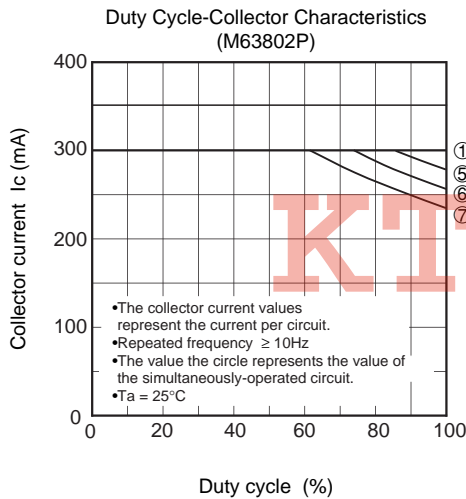
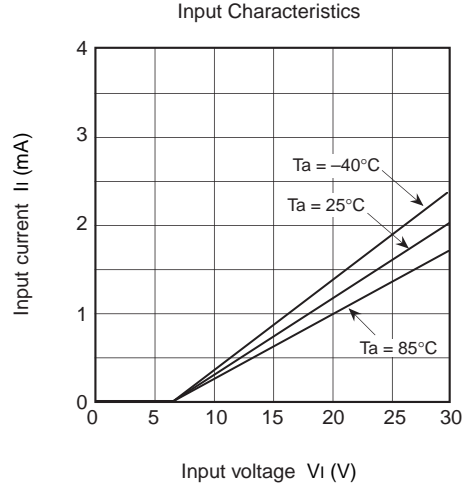
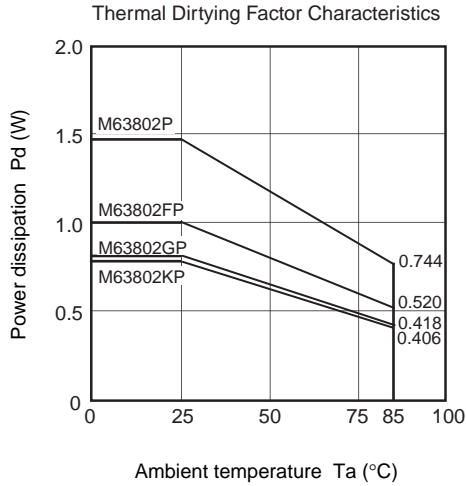


- (1) Pulse generator (PG) characteristics : PRR = 1kHz,
tw = 10μs, tr = 6ns, tf = 6ns, Zo = 50Ω, V_{IH} = 18V
- (2) Input-output conditions : R_L = 220Ω, V_o = 35V
- (3) Electrostatic capacity C_L includes floating capacitance at connections and input capacitance at probes

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TYPICAL CHARACTERISTICS



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